MIC5891

8-Bit Serial-Input Latched Source Driver

Features

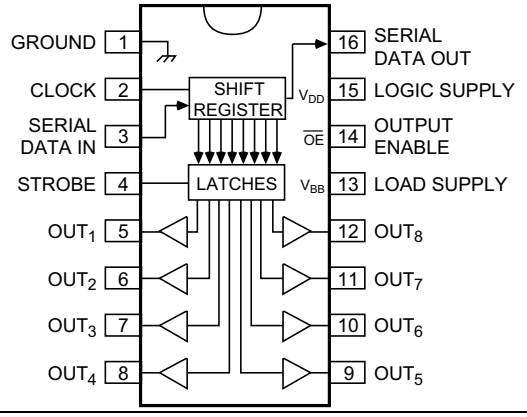
- High-Voltage, High-Current Outputs
- Output Transient Protection Diodes
- CMOS-, PMOS-, NMOS-, and TTL-Compatible Inputs
- 5 MHz Typical Data Input Rate
- Low-Power CMOS Latches

Applications

- Alphanumeric and Bar Graph Displays
- LED and Incandescent Displays
- Relay and Solenoid Drivers
- Other High-Power Loads

Package Type

MIC5891
16-PIN PDIP OR SOICW



General Description

The MIC5891 latched driver is a high-voltage, high-current integrated circuit comprised of eight CMOS data latches, CMOS control circuitry for the common STROBE and OUTPUT ENABLE, and bipolar Darlington transistor drivers for each latch.

Bipolar/MOS construction provides extremely low power latches with maximum interface flexibility.

The MIC5891 will typically operate at 5 MHz with a 5V logic supply.

The CMOS inputs are compatible with standard CMOS, PMOS, and NMOS logic levels. TTL circuits may be used with appropriate pull-up resistors to ensure a proper logic-high input.

A CMOS serial data output allows additional drivers to be cascaded when more than 8 bits are required.

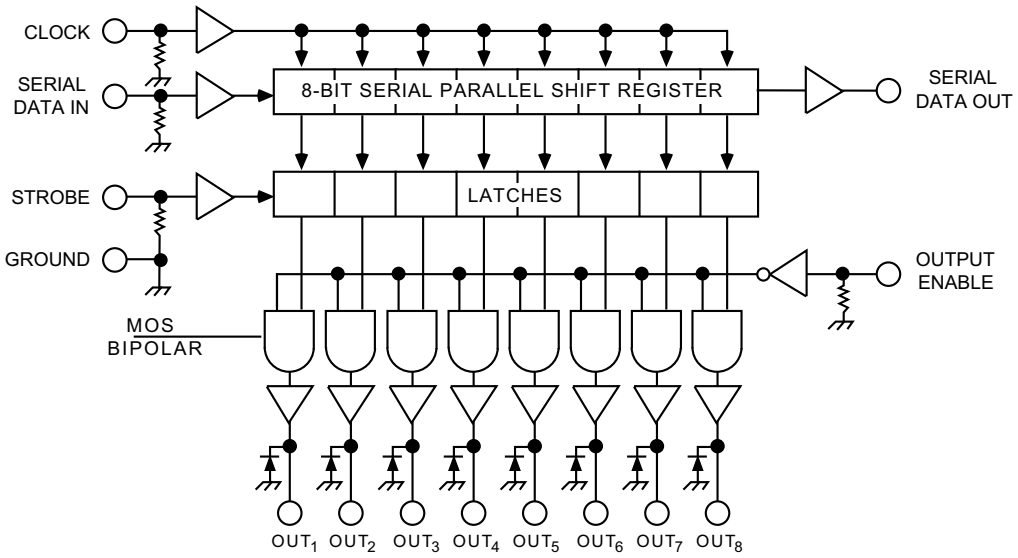
The MIC5891 has open-emitter outputs with suppression diodes for protection against inductive load transients. The output transistors are capable of sourcing 500 mA and will sustain at least 35V in the on-state.

Simultaneous operation of all drivers at maximum rated current requires a reduction in duty cycle due to package power limitations. Outputs may be paralleled for higher load current capability.

The MIC5891 is available in a 16-pin plastic DIP package (N) and 16-pin wide SOIC package (WM).

Functional Diagram

MIC5891
16-PIN PDIP OR SOICW



1.0 ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings † (Note 1, Note 2, Note 3)

Output Voltage (V_{OUT}) ..... +50V
Logic Supply Voltage Range (V_{DD}) ..... +4.5V to +15V
Load Supply Voltage Range (V_{BB}) ..... +5.0V to +50V
Input Voltage Range (V_{IN}) ..... –0.3V to (V_{DD} + 0.3V)
Continuous Collector Current (I_C) ..... 500 mA
Package Power Dissipation ..... See Figure 2-1

† **Notice:** Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operational sections of this specification is not intended. Exposure to maximum rating conditions for extended periods may affect device reliability.

Note 1: T_A = +25°C.

2: Derate at the rate of 20 mW/°C above T_A = +25°C.

3: Microchip CMOS devices have input-static protection, but are susceptible to damage when exposed to extremely high static electrical charges.

TABLE 1-1: ALLOWABLE DUTY CYCLES

Number of Outputs ON at I_{OUT} = –200 mA	Maximum Allowable Duty Cycles at a T_A of:		
	+50°C	+60°C	+70°C
8	53%	47%	41%
7	60%	54%	48%
6	70%	64%	56%
5	83%	75%	67%
4	100%	94%	84%
3	100%	100%	100%
2	100%	100%	100%
1	100%	100%	100%

TABLE 1-2: ELECTRICAL CHARACTERISTICS

Electrical Characteristics: V_{BB} = 50V, V_{DD} = 5V to 12V; T_A = 25°C, unless noted. **(Note 1)**.						
Parameters	**Sym.**	**Min.**	**Typ.**	**Max.**	**Units**	**Conditions**
Output Leakage Current	I_{CEX}	—	—	–50	µA	T_A = +25°C
		—	—	–100	µA	T_A = +85°C
Output Saturation Voltage	$V_{CE(SAT)}$	—	—	2.3	V	I_{OUT} = –100 mA, T_A = +85°C
		—	—	2.4	V	I_{OUT} = –225 mA, T_A = +85°C
		—	—	2.5	V	I_{OUT} = –350 mA, T_A = +85°C
Output Sustaining Voltage	$V_{CE(SUS)}$	35	—	—	V	I_{OUT} = –350 mA, L = 2 mH
Input Voltage	$V_{IN(1)}$ $V_{IN(0)}$	3.5	—	V_{DD}+0.3	V	V_{DD} = 5.0V
		10.5	—	V_{DD}+0.3	V	V_{DD} = 12V
		V_{SS}–0.3	—	0.8	V	V_{DD} = 5.0V to 12V
Input Current	$I_{IN(1)}$	—	—	120	µA	V_{DD} = V_{IN} = 5.0V
		—	—	240	µA	V_{DD} = 12V
Input Impedance	Z_{IN}	100	—	—	kΩ	V_{DD} = 5.0V
		50	—	—	kΩ	V_{DD} = 12V
Maximum Clock Frequency	f_c	3.3	—	—	MHz	—
Serial Data Output Resistance	R_{OUT}	—	—	20	kΩ	V_{DD} = 5.0V
		—	—	6.0	kΩ	V_{DD} = 12V
Turn-On Delay	t_{PLH}	—	—	2.0	µs	Output Enable to Output, I_{OUT} = –350 mA
Turn-Off Delay	t_{PHL}	—	—	10	µs	Output Enable to Output, I_{OUT} = –350 mA
Supply Current	I_{BB}	—	—	10	mA	All outputs on, all outputs open
		—	—	200	µA	All outputs off
	I_{DD}	—	—	100	µA	V_{DD} = 5V, all outputs off, inputs = 0V
		—	—	200	µA	V_{DD} = 12V, all outputs off, inputs = 0V
		—	—	1.0	mA	V_{DD} = 5V, one output on, inputs = 0V
		—	—	3.0	mA	V_{DD} = 12V, one output on, inputs = 0V
Diode Leakage Current	I_H	—	—	50	µA	T_A = +25°C; Max. V_{BB}
		—	—	100	µA	T_A = +85°C; Max. V_{BB}
Diode Forward Voltage	V_F	—	—	2.0	V	I_F = 350 mA; V_{BB} open

Note 1: Specification for packaged product only.

2: Positive (negative) current is defined as going into (coming out of) the specified device pin.

3: Operation of these devices with standard TTL may require the use of appropriate pull-up resistors.

TEMPERATURE SPECIFICATIONS

Parameters	Sym.	Min.	Typ.	Max.	Units	Conditions
Temperature Ranges						
Operating Temperature Range	T_A	–40	—	+85	°C	Note 1
Storage Temperature Range	T_S	–65	—	+150	°C	—

Note 1: The maximum allowable power dissipation is a function of ambient temperature, the maximum allowable junction temperature and the thermal resistance from junction to air (i.e., T_A, T_J, θ_{JA}). Exceeding the maximum allowable power dissipation will cause the device operating junction temperature to exceed the maximum +125°C rating. Sustained junction temperatures above +125°C can impact the device reliability.

Typical Circuits

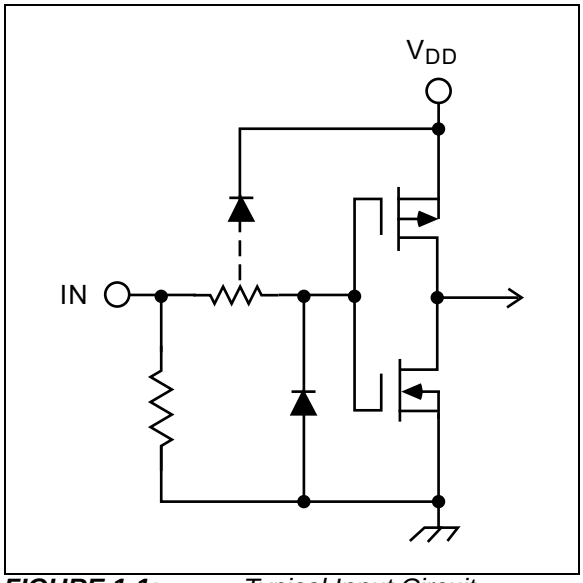


FIGURE 1-1: *Typical Input Circuit*

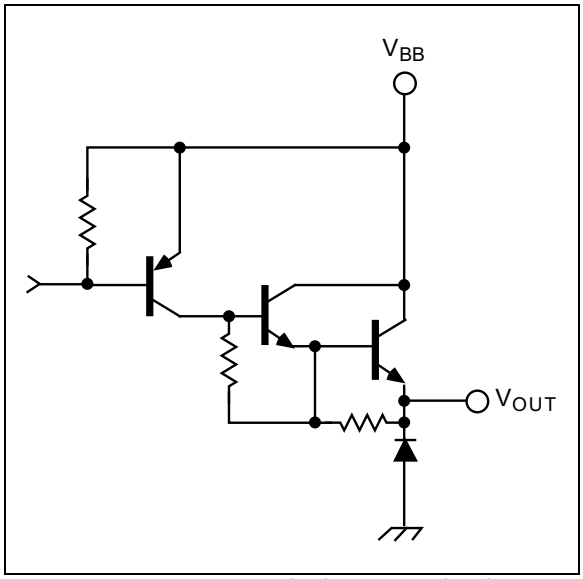


FIGURE 1-2: *Typical Output Circuit.*

2.0 TYPICAL PERFORMANCE CURVES

Note:	The graphs and tables provided following this note are a statistical summary based on a limited number of samples and are provided for informational purposes only. The performance characteristics listed herein are not tested or guaranteed. In some graphs or tables, the data presented may be outside the specified operating range (e.g., outside specified power supply range) and therefore outside the warranted range.

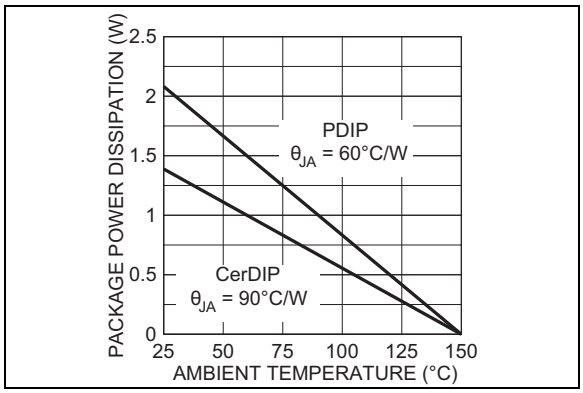


FIGURE 2-1: *Allowable Package Power Dissipation vs. Temperature.*

3.0 TIMING CONDITIONS

The descriptions of the timing conditions are listed below Figure 3-1.

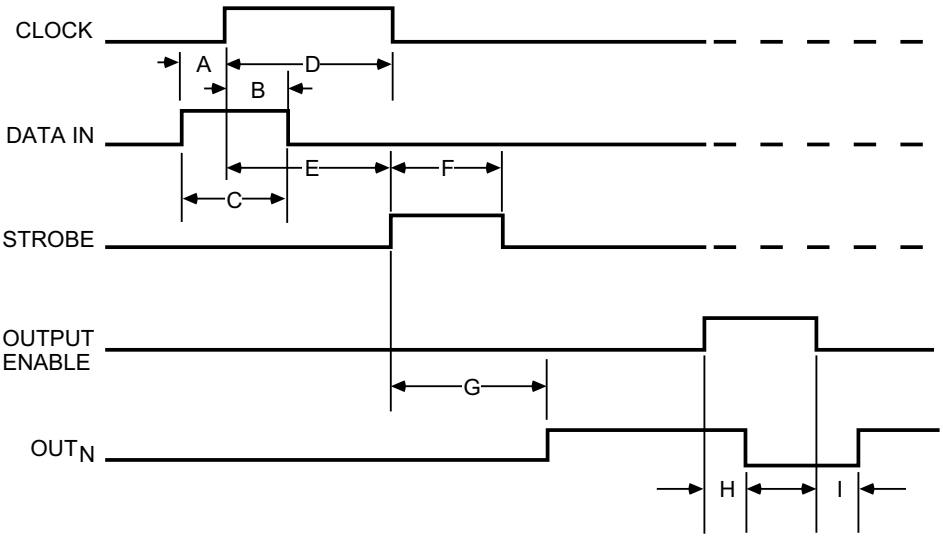


FIGURE 3-1: *Timing Conditions.*

TABLE 3-1: TIMING CONDITIONS PARAMETERS

V_{DD} = 5.0V, Logic levels are V_{DD} and ground.		
Reference	**Parameter**	**Value**
A	Minimum data active time before clock pulse (data set-up time)	75 ns
B	Minimum data active time after clock pulse (data hold time)	75 ns
C	Minimum data pulse width	150 ns
D	Minimum clock pulse width	150 ns
E	Minimum time between clock activation and strobe	300 ns
F	Minimum strobe pulse width	100 ns
G	Typical time between strobe activation and output transition	1.0 µs
H	Turn-off delay	See Electrical Characteristics
I	Turn-on delay	See Electrical Characteristics

TABLE 3-2: TRUTH TABLE

Serial Data Input	**Clock Input**	**Shift Register Contents**	**Serial Data Output**	**Strobe Input**	**Latch Contents**	**Output Enable**	**Output Content**
		I_1 I_2 I_3 ... I_{N-1} I_N			**I_1 I_2 I_3 ... I_{N-1} I_N**		**I_1 I_2 I_3 ... I_{N-1} I_N**
H	↑	H R_1 R_2 ... R_{N-2} R_{N-1}	R_{N-1}	—	—	—	—
L	↑	L R_1 R_2 ... R_{N-2} R_{N-1}	R_{N-1}				
X	↓	R_1 R_2 R_3 ... R_{N-1} R_N	R_N				
—	—	X X X ... X X	X	L	R_1 R_2 R_3 ... R_{N-1} R_N		
		P_1 P_2 P_3 ... P_{N-1} P_N	P_N	H	P_1 P_2 P_3 ... P_{N-1} P_N	L	P_1 P_2 P_3 ... P_{N-1} P_N
		—	—	—	X X X ... X X	H	L L L ... L L

L = Low Logic Level, H = High Logic Level, X = Irrelevant, P = Present State, R = Previous State.

4.0 APPLICATION INFORMATION

Serial data present at the input is transferred into the shift register on the rising edge of the CLOCK input pulse. Additional CLOCK pulses shift data information towards the SERIAL DATA OUTPUT. The serial data must appear at the input prior to the rising edge of the CLOCK input waveform.

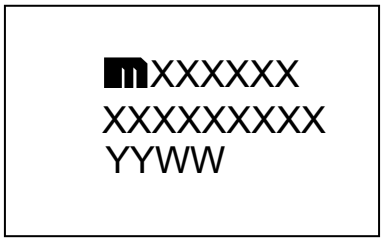
The 8 bits present in the shift register are transferred to the respective latches when the STROBE is high (serial-to-parallel conversion). The latches will continue to accept new data as long as the STROBE is held high. Most applications where the latching feature is not used (STROBE tied high) require the OUTPUT ENABLE input to be high during serial data entry.

Outputs are active (controlled by the latch state) when the OUTPUT ENABLE is low. All outputs are low (disabled) when the OUTPUT ENABLE is high. OUTPUT ENABLE does not affect the data in the shift register or latch.

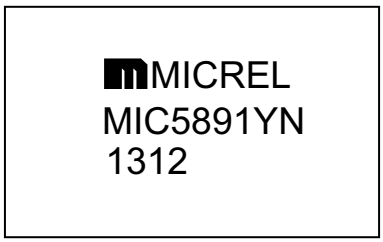
5.0 PACKAGING INFORMATION

5.1 Package Marking Information

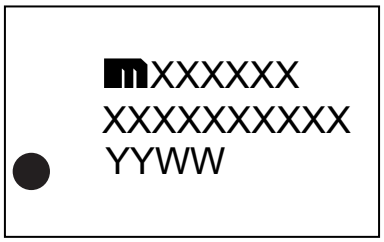
16-Pin PDIP*



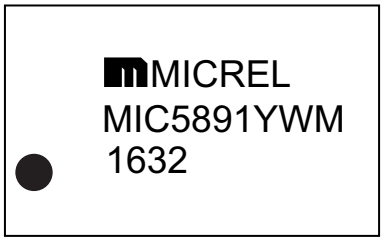
Example



16-Pin SOICW*



Example



Legend:	XX...X	Product code or customer-specific information
	Y	Year code (last digit of calendar year)
	YY	Year code (last 2 digits of calendar year)
	WW	Week code (week of January 1 is week ‘01’)
	NNN	Alphanumeric traceability code
	(e3)	Pb-free JEDEC® designator for Matte Tin (Sn)
	*	This package is Pb-free. The Pb-free JEDEC designator ((e3)) can be found on the outer packaging for this package.
	●, ▲, ▼	Pin one index is identified by a dot, delta up, or delta down (triangle mark).

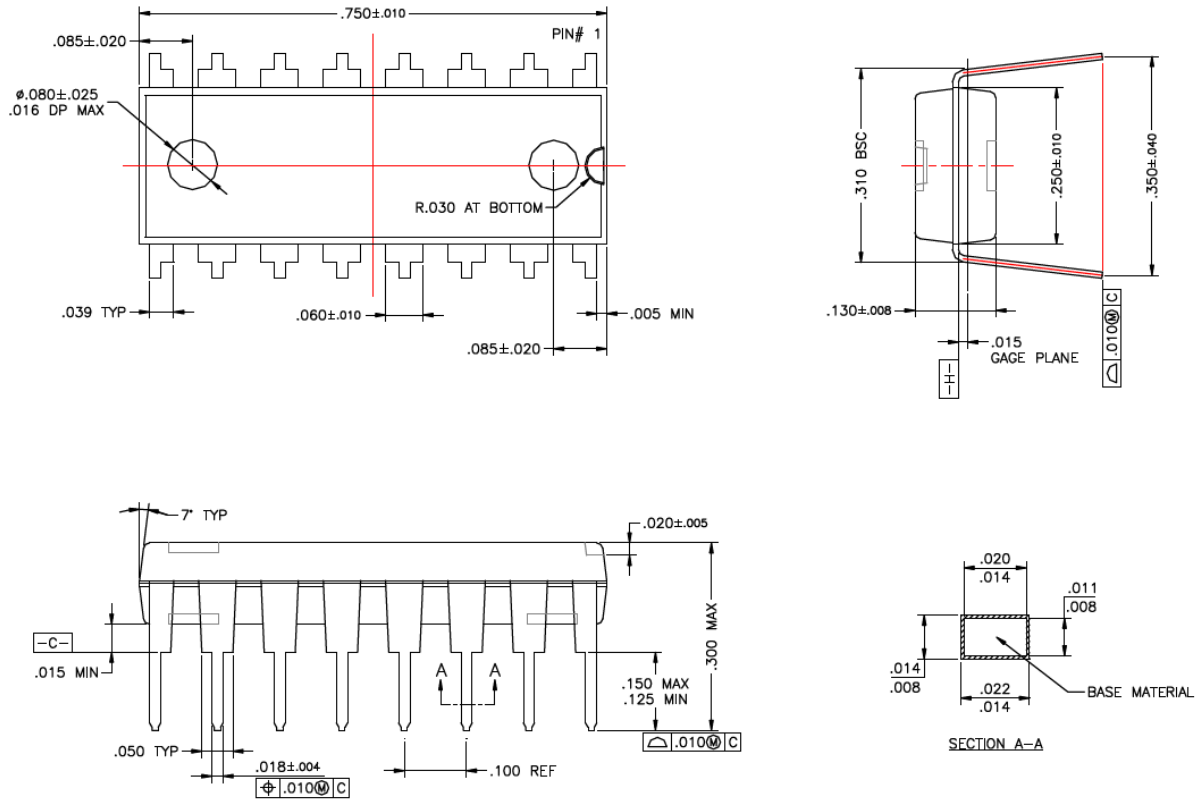
Note: In the event the full Microchip part number cannot be marked on one line, it will be carried over to the next line, thus limiting the number of available characters for customer-specific information. Package may or may not include the corporate logo.

Underbar (_) and/or Overbar (¯) symbol may not be to scale.

16-Lead PDIP Package Outline and Recommended Land Pattern

TITLE
16 LEAD PDIP PACKAGE OUTLINE & RECOMMENDED LAND PATTERN

DRAWING #	PDIP-16LD-PL-1	UNIT	INCH
LEAD FRAME	Copper	LEAD FINISH	Matte Tin

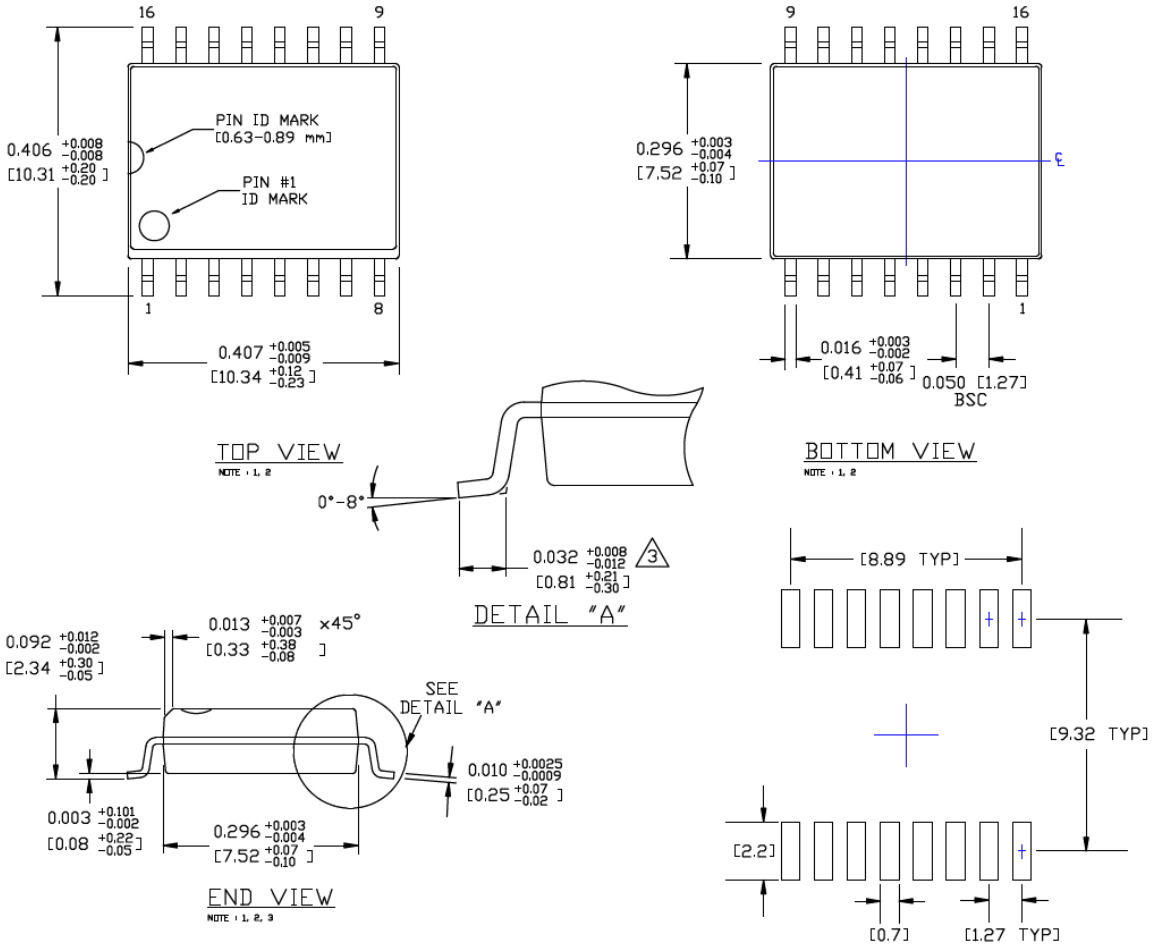


Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging.

16-Lead SOICW Package Outline and Recommended Land Pattern

TITLE
16 LEAD SOICW PACKAGE OUTLINE & RECOMMENDED LAND PATTERN

DRAWING #	SOICW-16LD-PL-1	UNIT	INCH [MM]



NOTES:
1. DIMENSIONS ARE IN INCHES[MM].
2. CONTROLLING DIMENSION: INCHES.
3. DIMENSION DOES NOT INCLUDE MOLD FLASH OR PROTRUSIONS, EITHER OF WHICH SHALL NOT EXCEED 0.006[0.15] PER SIDE.

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging.

NOTES:

APPENDIX A: REVISION HISTORY

Revision A (October 2016)

- Converted Micrel document MIC5891 to Microchip data sheet DS20005638A.
- Minor text changes throughout.
- Operating temperature range corrected in the Temperature Specifications section.
- Maximum Saturation Voltage values updated in Table 1-2.
- First Input Current maximum value updated in Table 1-2.

NOTES:

PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, contact your local Microchip representative or sales office.

PART NO.	X	XX	–	X.X
Device	Junction Temperature Range	Package		Media Type

Device:	MIC5891:	8-Bit Serial-Input Latched Source Driver
Junction Temperature Range:	Y =	–40°C to +85°C
Package:	N =	16-Lead PDIP
	WM =	16-Lead SOICW
Media Type:	TR =	1,000/Reel for WM Package
	(blank)=	25/Tube for N Package
	(blank)=	47/Tube for WM Package

Examples:

a) MIC5891YN: 8-Bit Serial-Input Latched Source Driver, –40°C to +85°C Junction Temperature Range, 16-Lead PDIP, 25/Tube

a) MIC5891YWM: 8-Bit Serial-Input Latched Source Driver, –40°C to +85°C Junction Temperature Range, 16-Lead SOICW, 47/Tube

a) MIC5891YWM-TR: 8-Bit Serial-Input Latched Source Driver, –40°C to +85°C Junction Temperature Range, 16-Lead SOICW, 1,000/Reel

NOTES:

Note the following details of the code protection feature on Microchip devices:

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- Microchip believes that its family of products is one of the most secure families of its kind on the market today, when used in the intended manner and under normal conditions.
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